



BCX5616Q

80V NPN MEDIUM POWER TRANSISTORS IN SOT89

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Leads,
 Solderable per MIL-STD-202 Method 208 @3
- Weight: 0.055 grams (Approximate)

Features

- BV_{CEO} > 80V
- I_c = 1A High Continuous Collector Current
- I_{CM} = 2.0A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Epitaxial Planar Die Construction
- Complementary PNP types: BCX5316Q
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The BCX5616Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

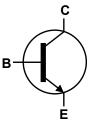
https://www.diodes.com/quality/product-definitions/

Applications

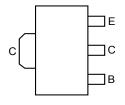
- Automotive
- Medium Power Switching or Amplification Applications
- AF Driver and Output Stages



Top View



Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

Ī	Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
	BCX5616QTA	Automotive	BL	7	12	1,000
	BCX5616QTC	Automotive	BI	13	12	4 000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



BL = Product Type Marking Code



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Collector-Base Voltage	V _{CBO}	100	V	
Collector-Emitter Voltage	V _{CEO}	80	V	
Emitter-Base Voltage	V _{EBO}	6	V	
Continuous Collector Current	Ic	1		
Peak Pulse Collector Current	I _{CM}	2.0	A	
Continuous Base Current	I _B	100	mA	
Peak Pulse Base Current	Івм	200	IIIA	

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1		
Power Dissipation	(Note 6)	P_{D}	1.5	W	
	(Note 7)		2.0	1	
	(Note 5)		125		
Thermal Resistance, Junction to Ambient Air	(Note 6)	R _{0JA}	83	°C/W	
	(Note 7)		60		
Thermal Resistance, Junction to Lead	$R_{ heta JL}$	13	°C/W		
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

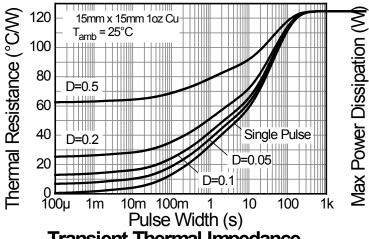
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

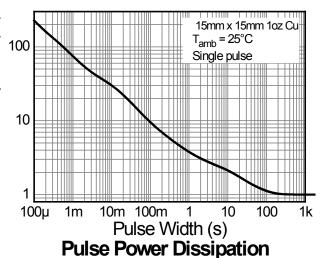
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (6), except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (6), except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

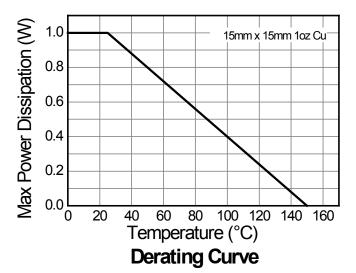


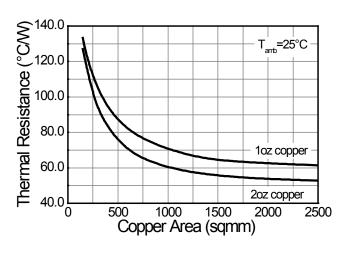
Thermal Characteristics and Derating Information

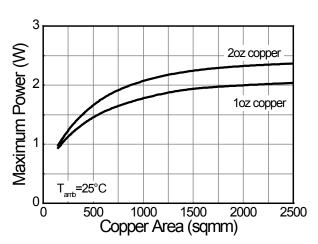




Transient Thermal Impedance





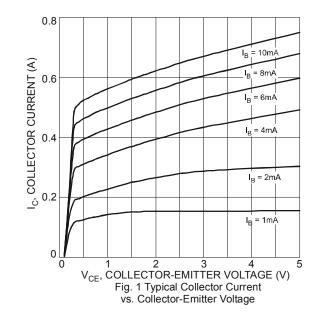


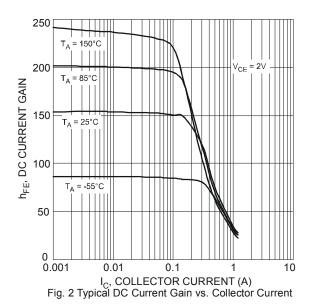


Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

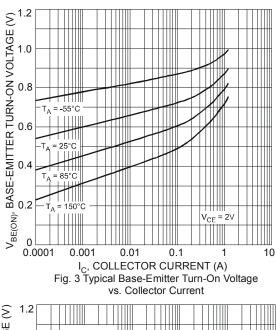
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	100	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	80	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	6	_	_	٧	I _E = 100μA
Collector Cut-off Current	Ісво	_	_	0.1 20	μА	V _{CB} = 30V V _{CB} = 30V, T _A = +150°C
Emitter Cut-off Current	I _{EBO}	_	_	20	nA	V _{EB} = 5V
Static Forward Current Transfer Ratio (Note 10)	h _{FE}	25 100 25	_ _ _	_ 250 _		$I_C = 5mA, V_{CE} = 2V$ $I_C = 150mA, V_{CE} = 2V$ $I_C = 500mA, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	_	_	0.5	٧	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	_	_	1.0	٧	I _C = 500mA, V _{CE} = 2V
Transition Frequency	f⊤	150	_	_	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance	Cobo	_	_	25	pF	V _{CB} = 10V, f = 1MHz

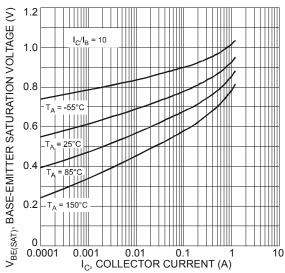
Notes: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

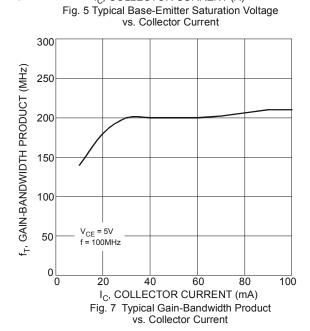












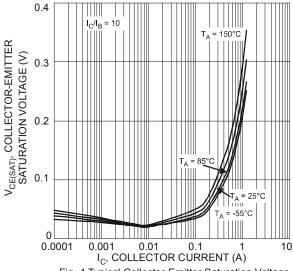


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

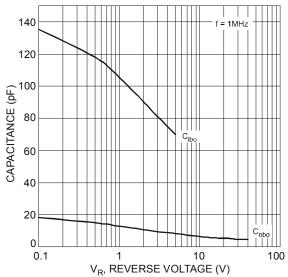
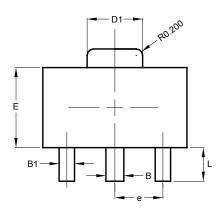


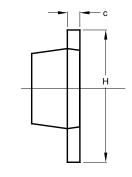
Fig. 6 Typical Capacitance Characteristics

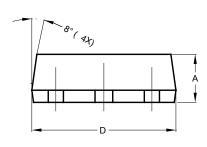


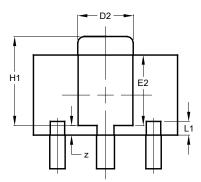
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.





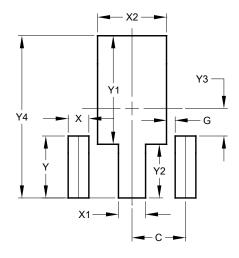




SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value
Dillielisions	(in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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